



2.5GHz Frequency Synthesiser

Preliminary Information

DS4583 1.6 October1997

The WL800 is a low power single chip frequency synthesiser. The circuit is fabricated on Mitel Semiconductor HG process and operates from a supply voltage of 2.7 - 3.6V. It is designed to work with the Mitel Semiconductor WL600C RF and IF circuit and the WL102 WLAN controller chip which together make up the DE6038 frequency hopping Wireless Local Area Network (WLAN) transceiver.

FEATURES

- Low power consumption
- 2.5GHz input
- 144 frequencies, 1MHz steps (20MHz crystal)
- Forms complete phase locked loop using external VCO and loop components
- Serially programmed via 3 wire bus
- Contains anti-modulation circuit
- Part of DE6038 Chip-set (WL600C, WL102)

ORDERING INFORMATION

WL800/KG/TP1R

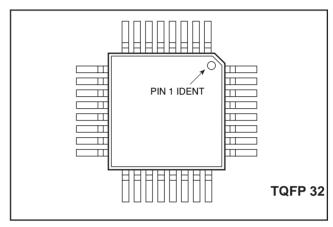


Fig.1 Pin connections - top view

RELATED DOCUMENTS

WL600C, WL102 datasheets

ABSOLUTE MAXIMUM RATINGS

Supply Voltage Vcc 4VDC
Transmit/Receive and -0.5VDC to Vcc +0.5VDC
Standby Input

Prescaler Inputs Pins 30 &31 No DC. Externally Capacitively

Coupled.

Output Current (any output)

Junction temperature Tj

ESD protection:

Operating temperature

TBD mA

150°C

2kV

Operating temperature

-20 to +85°C

DEVICE PIN OUT

PIN	REFERENCE	TYPE	DESCRIPTION	
1	VCC1	VCC	Power for serial data bus	
2	CS-DATA	IN	Channel Data in (Synth Programming)	
3	CS-CLK	IN	Data Clock (Synth Programming)	
4	CS-LOADB	IN	Data Enable (Synth Programming)	
5	STDBYB	IN	Power down control Active = Logic 1 Standby = logic 0	
6	VEE1	GND	Ground connection	
7	ISET		Set modulation current	
8	ICP		Set charge pump current	
9	VEE3	GND	Ground connection	
10	TXD	IN	Modulation data in	
11	COM CAP		Compensation capacitor for modulation data	
12	RCOMP	OUT	Resistor for V/I converter	
13	IDOUT	OUT	Modulation data out	
14	TXRXB	IN	Transmit/Receive control Transmit = Logic 1 Receive = Logic 0	
15	VARICAP	OUT	Control V to varicap in VCO	
16	VCC3	VCC	Power for charge pump and loop amplifier and modulator	
17	LOOPFILTER	OUT	Loop filter out (Loop Filter Components)	
18	CPUMPREF		Charge pump reference voltage	
19	CPUMPOUT	OUT	Charge pump out (Loop Filter Components)	
20	VEE2	GND	Ground connection	
21	SYSCLK	OUT	Reference (system) clock out	
22	XTAL		Crystal connection (Differential)	
23	XTALB		Crystal connection (Differential)	
24	VCC2	VCC	Power for reference oscillator	
25	FREF	OUT	Reference frequency monitor	
26	LKCAP		Lock detect capacitor	
27	LCKDETB	OUT	Lock detect output	
28	FV	OUT	VCO frequency / (NM+A) monitor	
29	VEE5	GND	Ground connection	
30	VCC	VCC	Power for prescaler, AM counter Ref divider, phase detector and	
			lock detector	
31	VCOIPB	IN	Prescaler IN-	
32	VCOIP	IN	Prescaler IN+	

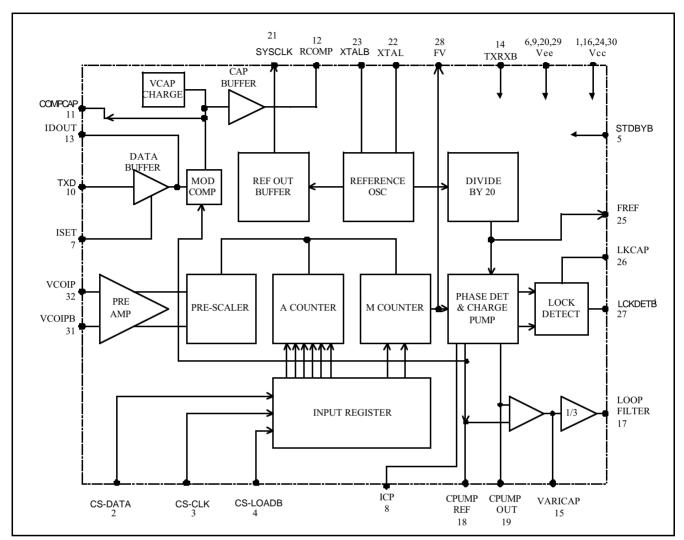


Fig. 1 WL800 block diagram

ELECTRICAL CHARACTERISTICS

These characteristics are guaranteed over the following conditions (unless otherwise stated): $T_{AMB} = -20$ °C, to +85 °C, Vcc = 2.7V to 3.6V

Characteristic		Value		Unit	Condition	
	MIN	TYP	MAX			
Supply current (total)						
Transmit		37	50	mA		
Receive		35	50	mA		
Supply current in standby		3	5	mA		
PROGRAMMING INPUTS						
Logic low voltage	0		0.4	V		
Logic high voltage	0.8Vcc		Vcc	V		
Input current			1	μΑ	Input level high	
Data clock frequency (1/tclock)			20	MHz	See Fig. 2	
Data/Enable set up time (t set up)	10			ns	See Fig. 2	
Enable hold time (t enable)	10			ns	See Fig. 2	
Positive clock pulse width (tp)	20			ns	See Fig. 2	
Negative clock pulse width (t neg)	20			ns	See Fig. 2	
STANDBY INPUT						
Logic low input voltage	0		0.8	V	Circuit powered down	
Logic high input voltage	Vcc -0.7		Vcc	V	Circuit powered up	
Input current		100	150	μΑ	Circuit powered up	
			-150	μΑ	Circuit powered down	
Standby to operate time		3		μs	*References operational (see note	
TX/RX INPUT						
Logic low input voltage	0		0.8	V	Receive mode	
Logic high input voltage	Vcc -0.7		Vcc	V	Transmit mode	
Input current			10	μΑ		
REFERENCE OUTPUT						
Reference output frequency		20		MHz	With 20MHz crystal	
Reference clock output voltage	200	250	300	mVp-p	With 15pF load	
Reference output impedance		600		Ohms		
Mark Space ratio	-2%	50/50	+2%		With 15pF load	
Rise time			15	ns		
Fall time			15	ns		
Crystal Drive Levels required		200		mV	Pins 22,23 differential	

ELECTRICAL CHARACTERISTICS (continued)

These characteristics are guaranteed over the following conditions (unless otherwise stated): $T_{AMB} = -20 \,^{\circ}\text{C}$, to +85 $^{\circ}\text{C}$, Vcc = 2.7V to 3.6V

Characteristic	Value			Unit	Condition	
	MIN	TYP	MAX			
LOCK DETECT CIRCUIT						
Smoothing capacitor charge/	80	110	150	μΑ	Determined by application.	
discharge current						
Threshold voltage		Vcc-0.3		V	On smoothing capacitor	
Output high voltage	1.8		Vcc	V	I out = $10\mu A$	
Output low voltage	Vee		0.5	V	I out = $0 \mu A$	
PHASE DETECTOR AND						
CHARGE PUMP						
Comparison frequency		1		MHz	Divided crystal reference	
Charge pump output current		±1		mA	Rpin 8 = 10k	
Up down current matching			5	%		
Reference voltage	Vcc-1.05		Vcc-0.7	V		
CHARGE PUMP OP-AMP						
First Stage:						
High output voltage	2.4			V		
Low output voltage			0.3	V		
Second Stage:						
Filter drive amplifier output current		±1		mA		
Filter drive amp output swing		0.77		Vp-p		
DDEGGAL ED						
PRESCALER	40		000			
Input drive voltage	40		200	mV rms		
Maximum operating frequency	3	0000		GHz		
Input Impedance		330Ω				
		0.5pF				
TRANSMIT DATA INPUT						
Logic low	-60		-100	μΑ	Rsource=20k	
Logic high	+60		+100	μΑ		
TX DATA OUT						
Logic 0 output current	25	50	100	μΑ	Set by external resistor on pin 7	
Logic 1 output current			200	nA	Leakage Current	
Output current in receive mode		25		μΑ	Equal to 0.5 mod current	

ELECTRICAL CHARACTERISTICS (continued)

These characteristics are guaranteed over the following conditions (unless otherwise stated): $T_{AMB} = -20 \,^{\circ}\text{C}$, to +85 $^{\circ}\text{C}$, Vcc = 2.7V to 3.6V

Characteristic		Value		Unit	Condition
	MIN	TYP	MAX		
MOD. CURRENT INPUT					
Mod current set pin current		25		μΑ	Set by external resistor on pin 7. R = 47k
COMPENSATION CAP PIN					
Compensation current		-25		μΑ	Set by external resistor on pin 7. R=47k.
Compensation current matching			2	%	Compensation capacitor 8.2nF
Compensation capacitor voltage	CPRef - 0.02	CPRef	CPRef +0.02	V	Receive mode
Compensation capacitor voltage	88	98	+110	mV	1 MHz data, 32bits '0'
	-120	-98	-88	mV	1 MHz data, 32bits '1'
VCAP CHARGE					
Settling Time			100	μs	Receive mode
Charging Current			20	mA	Receive mode.
					Vcap initially at 0 V.
Offset Voltage			15	mV	Receive mode.
COMPENSATION Vtol					
(CAPBUFFER+RCOMP)					
Compensation current into Loop		+52.08		nA	Per 1us of databit 0
Filter		-52.08		nA	Per 1us of databit 1
Max. Compensation current		1.666		mA	for 32 bits(1) at 1MHz
CAPACITOR BUFFER				.,	
Offset Voltage		15		mV	
External Resistor RCOMP		58000		Ohms	

Note: 1. Standby to operate time refers to the time for internal current references to become operational.

FUNCTIONAL DESCRIPTION

Reference Frequency

The reference frequency is generated using a 20MHz crystal in conjunction with an on chip oscillator maintaining circuit. A buffer circuit provides a low level voltage output signal at the crystal frequency to drive the logic in the protocol and control chip. The crystal frequency is divided by 20 to provide the reference signal to the phase comparator.

Counters / Dividers

An external oscillator is used to feed the input of the preamplifier in the synthesiser, (this isolates the counters from the oscillator and reduces the level of drive signal required by the synthesiser). The output of the preamplifier drives a dual modulus prescaler with ratios of 48/49, which in turn then drives the standard A-M counter arrangement. The A counter then provides the modulus control signal back to the prescaler. The counter system has an overall division ratio given by the formula MN+A where N is the lower divide ratio of the prescaler (48).

The divide ratio of the M and A counters is programmable to allow the oscillator to be tuned over the required frequency range of 144 channels at 1MHz spacing. The M count ratio can be programmed over the range 49 to 52 and the A counter from 1 to 48 giving a total divide ratio from 2353 to 2544 which is greater than necessary to tune the required frequency range.

Programming

The programming data for the synthesiser is entered via a three wire serial data bus consisting of Enable, Clock and Data signals.

The enable signal is taken low at the start of the programming sequence and remains low for the duration of the 8 serial data bits. A positive clock edge is required to strobe each data bit into the input register. When all 8 data bits are entered, the enable pin is taken high forcing the counters to zero and preloading the new count data when the counter is next clocked. The charge pump is disabled for a short period after the enable pin goes low to prevent glitch energy being transferred to the VCO.

Phase Detectors

A conventional digital phase frequency detector incorporating dead band suppression is used in conjunction with a charge pump to steer the VCO. An internal op-amp maintains the charge pump pin at the same voltage as the charge pump reference by virtual earth principles. The op-amp is split into two parts with the first section having a relatively low current drive capability but including the high gain stages of the amplifier. The second stage has a controlled voltage gain of 1/3 but high input impedance and low output impedance. This minimises loading to the high output impedance of the first stage and provides sufficient drive current via the loop filter to maintain virtual earth at the charge pump output. The output from the first stage is designed to swing close to the positive and negative rails so as to provide maximum voltage swing to the varactor controlling the VCO. A compensating capacitor can be connected to this point to stabilise the amplifier.

A lock detect output (active low) is provided to give an indication to the controller that the phase locked loop is locked, preventing transmission on illegal frequencies.

Antimodulation

The WL800 contains a data buffer circuit which accepts transmit data from the CMOS controller circuit and converts the CMOS input to a tristate current output for driving the transmit spectrum shaping filter. The buffer gives zero current for a logic "1" input, a high current (+2I) for a logic "0" and a current midway between the two (+I) for use during the transmit amplifier power up/down period and during receive. This function prevents the synthesiser centring its frequency on either a logic "1" or "0" and removes the possibility of overmodulation at the start of a transmission. The amplitude of the output current and therefore modulation index of the radio is controlled by an external resistor connected to ground. A data compensation path is included which counteracts the tendency of the PLL to drift back to centre frequency when the

tendency of the PLL to drift back to centre frequency when the data is non-white. This is achieved by charging an external capacitor with a current +I when data is low, and discharging it by a current -I when data is high. The capacitor voltage, which then represents an integrated form of the data is converted to a current via a buffer and an external resistor (RCOMP), and fed into the Loop Filter in addition to the Phase Detector output. During Receive Mode, the capacitor is charged to the Charge Pump Reference voltage.

WL800 PROGRAMMING

Frequency	A counter	M counter	6 bit binary A	bit binary M
MHz	Value	Value	Value d0-d5	Value d6-d7
2357	5	49	101000	00
2358	6	49	011000	00
2400	48	49	000011	00
2401	1	50	100000	10
2448	48	50	000011	10
2449	1	51	100000	01
2496	48	51	000011	01
2497	1	52	100000	11
2498	2	52	010000	11
2499	3	52	110000	11
2500	4	52	001000	11
1		l		1

Notes: 1.The binary data is in reverse order.

2. The data is programmed with bit d7 first and d0 last

	d0	d1	d2	d3	d4	d5	d6	d7
i	A counter							unter

TIMING DIAGRAM

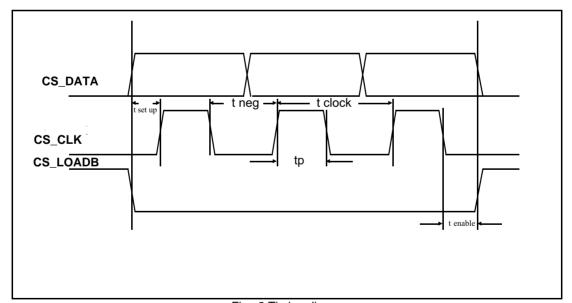
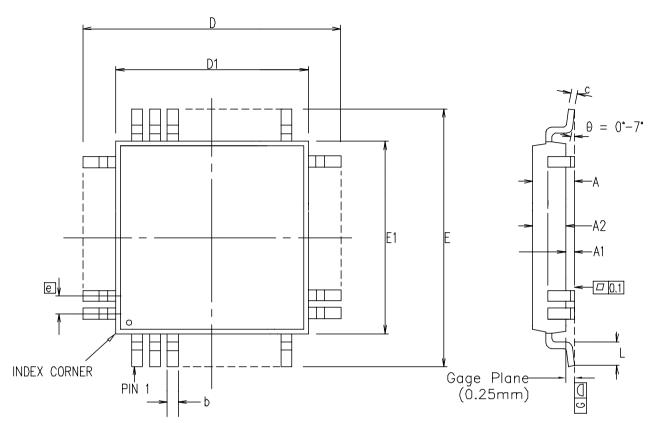


Fig. 2 Timing diagram

CONTROL SIGNALS

Control Line	Logic '0'	Logic '1'
STDBYB	Standby	Active
TXRXB	Receive	Transmit
LCKDETB	Locked	Unlocked



	Control D			Altern. D	imensions		
Symbol	in millir	metres		in inches			
,	MIN	MAX		MIN	MAX		
Α		1.20			0.047		
A1	0.05	0.15		0.002	0.006		
A2	0.95	1.05		0.037	0.041		
D	9.00	BSC		0.354	4 BSC		
D1	7.00	BSC		0.276 BSC			
E	9.00	BSC		0.354 BSC			
E1	7.00	BSC		0.276 BSC			
L	0.45	0.75		0.018	0.030		
е	0.80	BSC		0.031	1 BSC		
b	0.30	0.45		0.012	0.018		
С	0.09	0.20		0.004	0.008		
	Pin features						
N	32						
ND	8						
NE	8						
NOTE		S	QUAR	?E	_		

Conforms to JEDEC MS-026 ABA Iss. C

Notes:

- Pin 1 indicator may be a corner chamfer, dot or both.
 Controlling dimensions are in millimeters.
 The top package body size may be smaller than the bottom package body size by a max. of 0.15 mm.
 Dimension D1 and E1 do not include mould protusion.
 Dimension b does not include dambar protusion.
 Coplanarity, measured at seating plane G, to be 0.10 mm max.

This drawing supersedes 418/ED/51612/001 (Swindon)

© Mitel						ORIGINATING SITE: SWINDON
ISSUE	1	2				Title: Package Outline Drawing for 32 Ids TQFP (TP)
ACN	201348	207076		 MITEI	SEMICONDUCTOR	(7x7x1.0) mm, Body+2.0 mm
DATE	250CT96	6JUL99			SLIVIICONDOCTON	Drawing Number
APPROVED						GPD00233



http://www.mitelsemi.com

World Headquarters - Canada

Tel: +1 (613) 592 2122 Fax: +1 (613) 592 6909

Asia/Pacific

Tel: +65 333 6193 Fax: +65 333 6192 Europe, Middle East, and Africa (EMEA)

Tel: +44 (0) 1793 518528 Fax: +44 (0) 1793 518581

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North America

Tel: +1 (770) 486 0194

Fax: +1 (770) 631 8213